**Vishay Semiconductors** 

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# Hyperfast Rectifier, 8 A FRED Pt<sup>®</sup>



TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.5 V			
t <sub>rr</sub> (typ.)	14 ns			
T <sub>J</sub> max.	175 °C			
Package	TO-220 FullPAK 2L			
Circuit configuration	Single			

#### **FEATURES**

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V	
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 105 °C	8	A	
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	80		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	TEST CONDITIONS MIN.		MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-	
Forward voltage V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.5	3.4	V	
	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.5	2.0		
Deverse leekens ourrent	1	$V_{R} = V_{R}$ rated	-	0.02	30	
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	21	150	μA
Junction capacitance	CT	V <sub>R</sub> = 600 V		6	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8 -		-	nH	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	14	18	
Reverse recovery time	+	I <sub>F</sub> = 8 A, dI <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V		-	15	24	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 390 V	-	17	-	- ns - - A
		T <sub>J</sub> = 125 °C		-	33	-	
Peak recovery current		T <sub>J</sub> = 25 °C		-	2.6	-	
Feak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	4.3	-	
Powerce recevery charge		T <sub>J</sub> = 25 °C		-	22	-	nC
Reverse recovery charge Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	77	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A, dI <sub>F</sub> /dt = 600 A/μs, V <sub>R</sub> = 390 V	-	26	-	ns
Peak recovery current	I <sub>RRM</sub>			-	11	-	А
Reverse recovery charge	Q <sub>rr</sub>			-	150	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	4.6	5.5	
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2	-	g
weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220 FullPAK 2L		ETX08	806FP	



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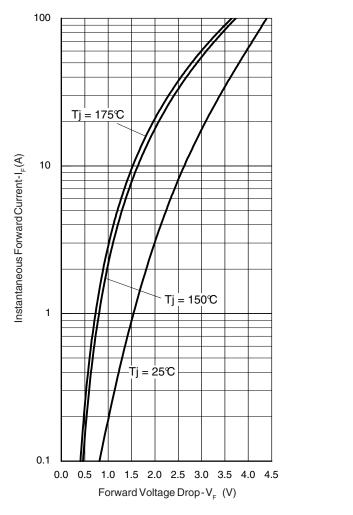


Fig. 1 - Typical Forward Voltage Drop Characteristics

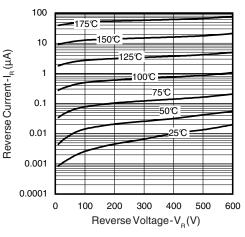


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

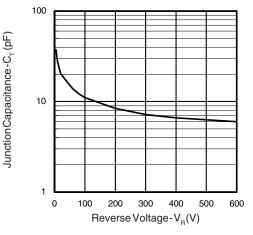
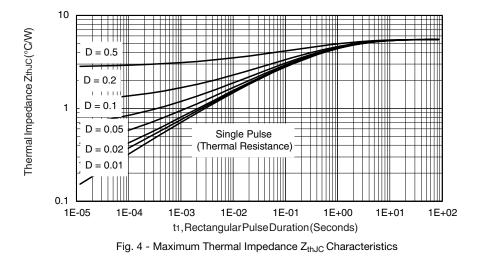


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



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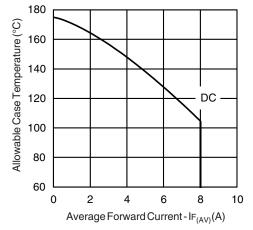


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

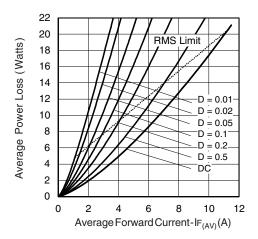
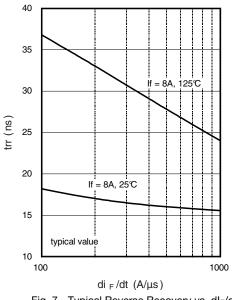
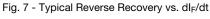


Fig. 6 - Forward Power Loss Characteristics





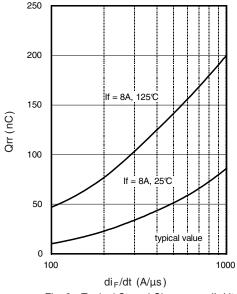


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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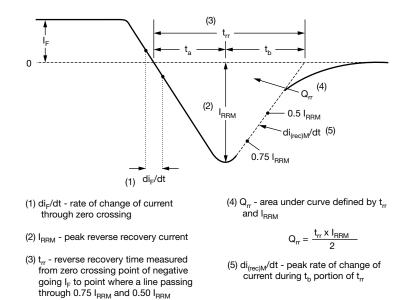
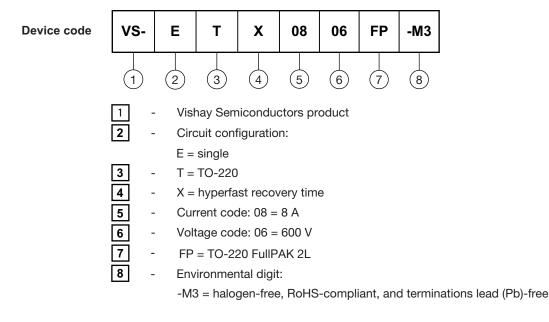


Fig. 9 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

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extrapolated to zero current.

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-ETX0806FP-M3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96157			
Part marking information	www.vishay.com/doc?95392			

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